



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

APPLICANTS: Yao-Sheng Lee  
SERIAL NUMBER: 10/616,492  
FILING DATE: 07/08/03  
TITLE: High Temperature Anisotropic Etching of Multi-Layer Structures  
ATTY DOCKET NO: 074361.00015

U.S. Patent and Trademark Office  
2011 South Clark Place  
Customer Window, Mail Stop Missing Parts  
Crystal Plaza Two, Lobby, Room 1B03  
Arlington, VA 22202

POWER OF ATTORNEY

Applicant's complete Assignee, Unaxis USA Inc. does hereby revoke all Powers of Attorney heretofore given and appoints Stefan V. Stein, Registration No. 29,702, Harvey S. Kauget, Registration No. 41,108, Michael J. Colitz, III, Registration No. 37,010, and Anderson L. Baldy III, Registration No. 40,496, as their attorneys in the above entitled application, with full power of substitution, association and revocation, to transact all business in the United States Patent and Trademark Office connected therewith.

Further, please send all correspondence to:

Harvey S. Kauget  
Holland & Knight LLP  
Suite 4100  
100 N. Tampa Street  
Tampa, Florida 33602-3644

Direct all telephone calls to Harvey S. Kauget at: (813) 227-8500

EXECUTED by me on this the 27<sup>th</sup> day of October, 2003, at St. Petersburg  
Florida.

Christopher Constantine

By: Christopher Constantine

Its: Chief Technical Officer



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**DECLARATION FOR PATENT APPLICATION**

As a below named inventor, I hereby declare that:

My residence, post office address and citizenship is as stated below next to my name;

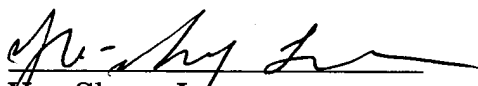
I believe that I am the original, first and joint inventor of the subject matter which is claimed and for which a patent is sought on the invention High Temperature Anisotropic Etching of Multi-Layer Structures, the specification of which claims priority to a provisional patent application Serial No. 60/397,185 filed July 19, 2002.

I hereby state that I have reviewed and understand the contents of the above-identified specification, including the claim, as amended by any amendment referred to above.

I acknowledge the duty to disclose information which is material to the examination of this application in accordance with Title 37, Code of Federal Regulations, Section 1.56(a).

I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and, further, that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

Date: 10/27/03

  
Yao-Sheng Lee

Citizenship: ~~Taiwan~~ *United States*

Residence and Post Office

Address:

~~1741 Oak Pond St.~~

~~Oldsmar, FL 34677~~

*12812 Stanwyck Circle  
Tampa, FL 33626*

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